

Electrostatic Discharged Protection Devices (ESD) Data Sheet

Description

UDT14A05L03 is surge rated diode arrays designed to protect high speed data interfaces. It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by electrostatic discharge (ESD), electrical fast transients (EFT), and lightning.

The unique design of the device incorporates one surge rated, and two data lines. Low capacitance steering diodes and a TVS diode in a single package. The low capacitance array configuration allows the user to protect two high speed data or transmission lines.

The two inductance construction minimizes voltage overshoot during high current surges.

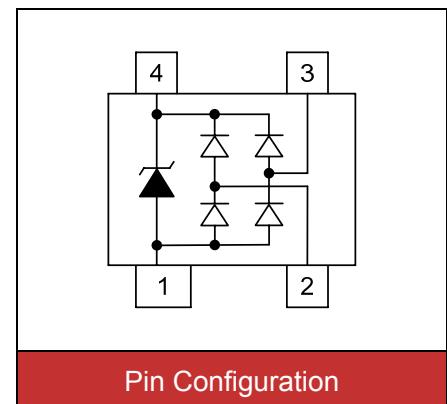


Contact : $\pm 8\text{kV}$
Air : $\pm 15\text{kV}$



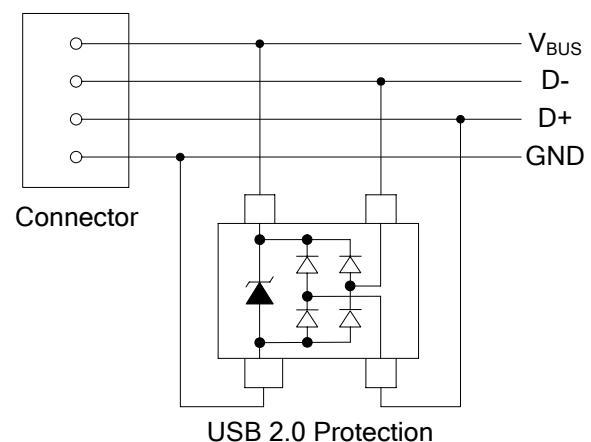
Features

- IEC61000-4-2 ESD 15KV Air, 8KV contact compliance
- SOT-143 surface mount package
- Protects two high-speed data lines and one power line
- Array of surge rated, low capacitance diodes
- Working voltage: 5V
- Low leakage current
- Low clamping voltage
- Solid-state silicon avalanche technology
- RoHS compliant
- Solder reflow temperature: Pure Tin-Sn, 260~270°C
- Flammability rating UL 94V-0
- Meets MSL level 1, per J-STD-020
- Marking: B T05



Applications

- USB power and data line protection
- Ethernet 10BaseT
- Video line protection
- I²C bus protection
- WAN/LAN equipment
- ISDN S/T interface
- Microcontroller input protection
- Portable electronics



Maximum Ratings

Rating	Symbol	Value	Unit
Peak pulse current ($t_p=8/20\mu s$ waveform)	I_{PP}	12	A
ESD voltage (Contact discharge)	V_{ESD}	± 8	kV
ESD voltage (Air discharge)		± 15	
Storage & operating temperature range	T_{STG}, T_J	-55~+150	°C

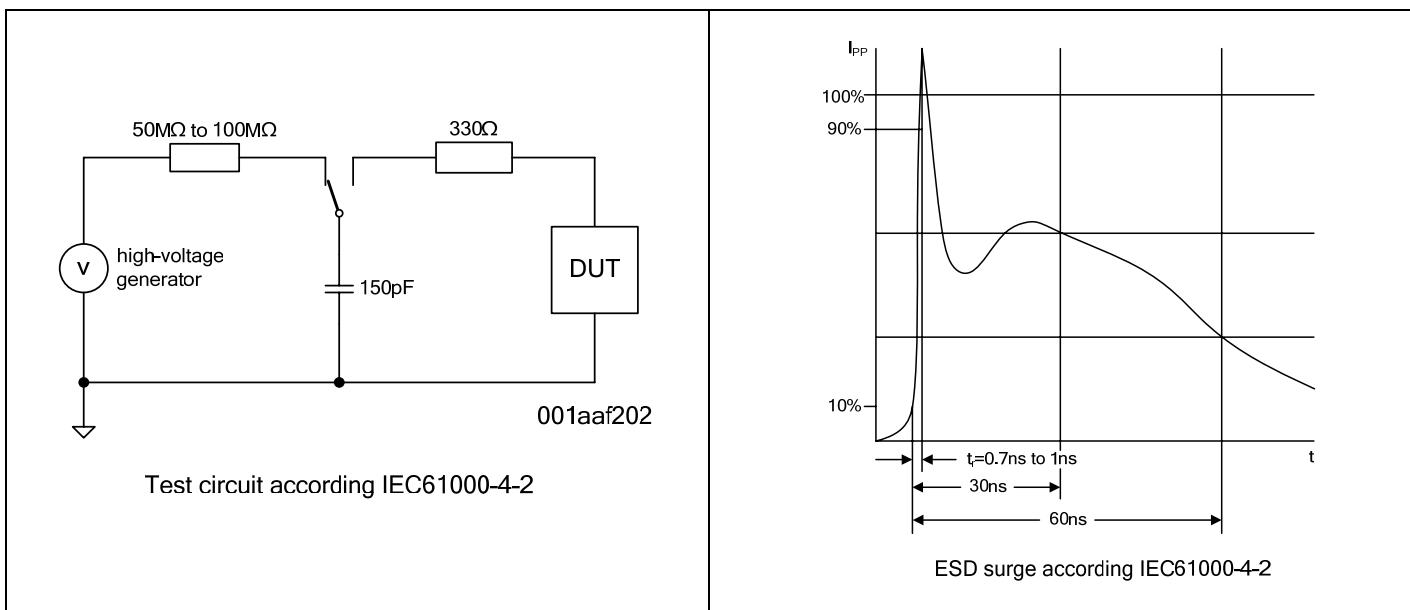
Electrical Characteristics ($T_J=25^\circ C$)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V_{RWM}				5	V
Reverse breakdown voltage	V_{BR}	$I_{BR}=1mA$	6			V
Reverse leakage current	I_R	$V_R=5V$			5	μA
Clamping voltage ($t_p=8/20\mu s$)	V_C	$I_{PP}=1A$			9.8	V
Clamping voltage ($t_p=8/20\mu s$)	V_C	$I_{PP}=12A$			25	V
Off state junction capacitance	C_J	0Vdc, $f=1MHz$ Between I/O pins and GND		1.5	3	pF

ESD Protection Standards

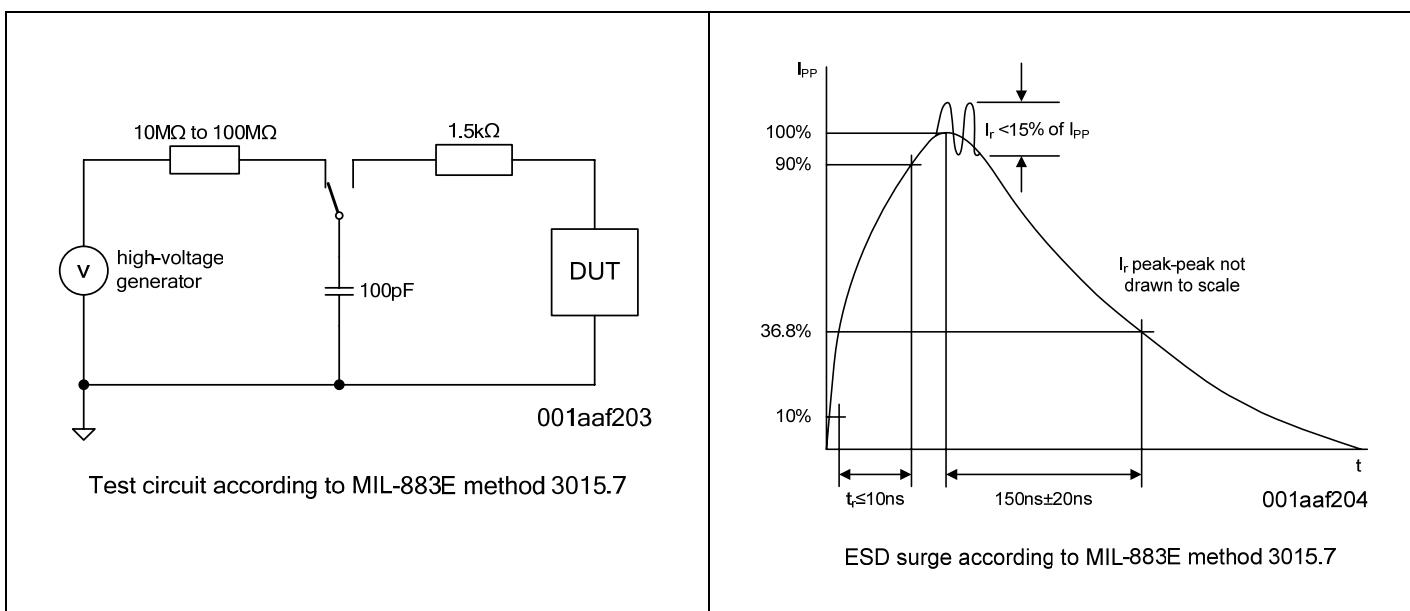
IEC61000-4-2

Interfaces of consumer electronic equipment are widely specified according to the International Electrotechnical Commission standard IEC61000-4-2. This standard is not targeted towards particular devices but towards general equipment, systems and subsystems that may be involved in electrostatic discharge. consists of a 150pF capacitor and a 330Ω series resistor representing the counterpart to the Device Under Test (DUT).



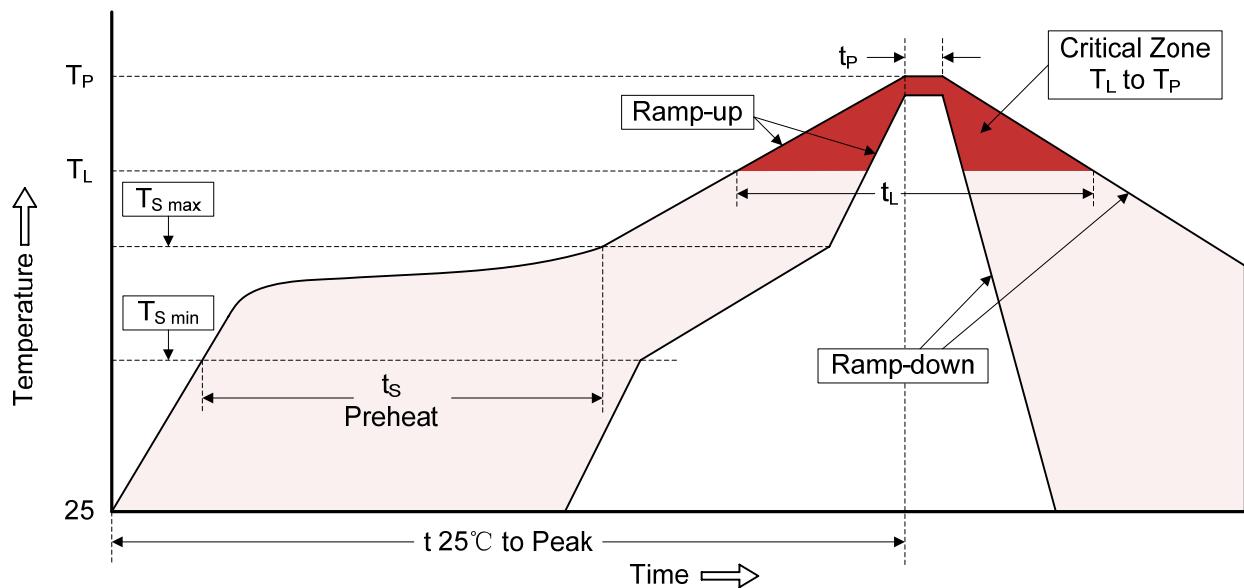
Human Body Model (HBM, MIL-883E method 3015.7)

The HBM standard simulates an ESD surge generated by human contact to electronic components.



Recommended Soldering Conditions

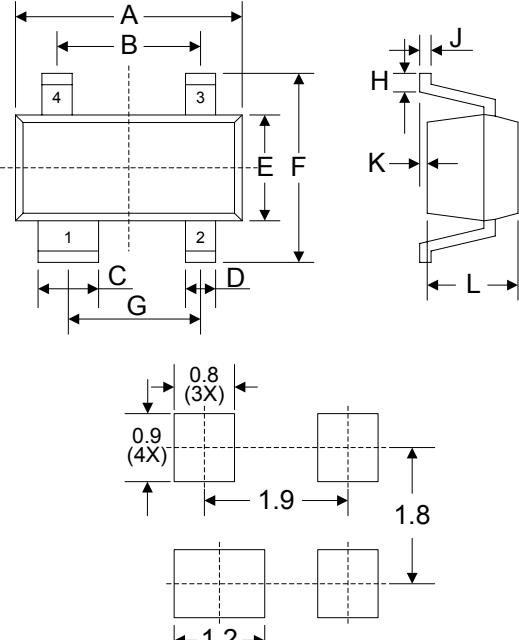
Reflow Soldering



Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	3°C/second max.
Preheat	
-Temperature Min ($T_{S\ min}$)	150°C
-Temperature Max ($T_{S\ max}$)	200°C
-Time (min to max) (t_S)	60-180 seconds
$T_{S\ max}$ to T_L	
-Ramp-up Rate	3°C/second max.
Time maintained above:	
-Temperature (T_L)	217°C
-Time (t_L)	60-150 seconds
Peak Temperature (T_P)	260°C
Time within 5°C of actual Peak Temperature (t_P)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

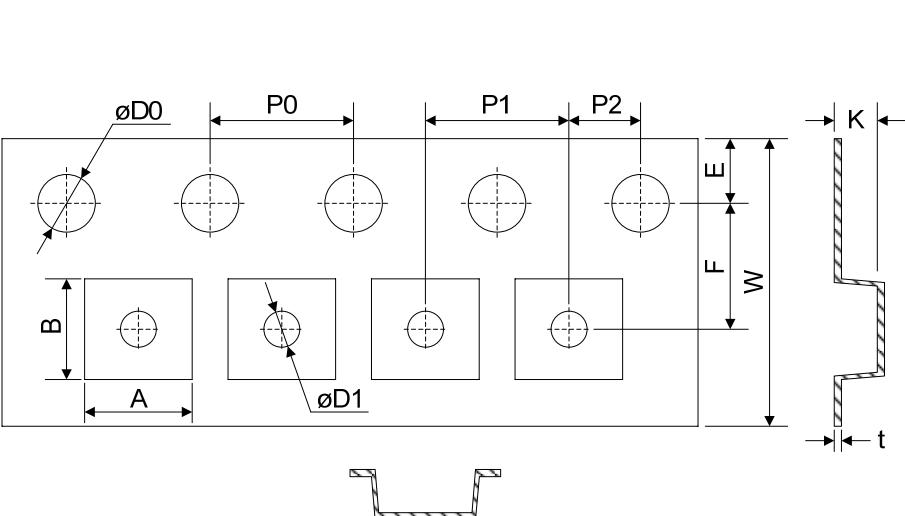
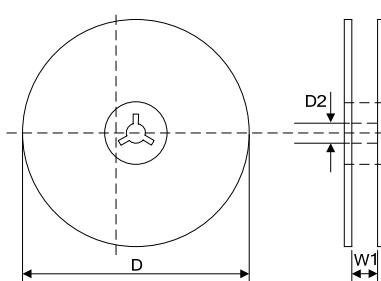
Dimensions (SOT-143)



The diagram shows the physical dimensions of the SOT-143 package. The top view indicates lead spacing (A), lead thickness (B), body width (E), body height (F), and body thickness (G). The side view shows lead height (H), lead pitch (J), body thickness (K), and body width (L). Below the main views is a detailed soldering pad layout with dimensions for the pads and the space between them.

Symbol	Dimension			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.79	3.04	0.110	0.120
B	1.90		0.075	
C	0.76	0.93	0.030	0.037
D	0.36	0.50	0.014	0.020
E	1.19	1.40	0.047	0.055
F	-	2.50	-	0.098
G	1.70		0.067	
H	0.15	-	0.006	-
J	0.08	0.15	0.003	0.006
K	-	0.13	-	0.005
L	-	1.14	-	0.045

Packaging

Tape	Symbol	Dimension (mm)
	W	8.00±0.30
	P0	4.00±0.10
	P1	4.00±0.10
	P2	2.00±0.10
	D0	Φ1.55±0.10
	D1	Φ1.05±0.05
	E	1.75±0.10
	F	3.50±0.10
	A	3.05±0.15
	B	2.78±0.15
	K	1.20±0.10
	t	0.20±0.05
Reel	D	Φ178.0±2.0
	D2	Φ13.0
	W1	9.5
	Quantity: 3000PCS	

Данный компонент на территории Российской Федерации**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибуторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ Р В 0015-002 и ЭС РД 009

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